Unit in mm

TLP227G

TOSHIBA Photocoupler Photo Relay

# **TLP227G,TLP227G-2**

Cordless Telephone

**PBX** 

Modem

The TOSHIBA TLP227G series consist of a gallium arsenide infrared emitting diode optically coupled to a photo–MOS FET in a plastic DIP package.

The TLP227G series are a bi-directional switch which can replace mechanical relays in many applications.

- TLP227G: 4 pin DIP(DIP4),1 channel type(1 form A)
- TLP227G-2: 8 pin DIP(DIP8),2 channel type(2 form A)
- Peak off-state voltage: 350V(min.)
- Trigger LED current: 3mA(max.)
- On-state current: 120mA(max.)
- On-state resistance:  $35\Omega(\text{max.})$
- Isolation voltage: 2500Vrms (min.)
- Isolation thickness: 0.4mm(min.)

BS EN60950-1: 2002, certificate no.8276

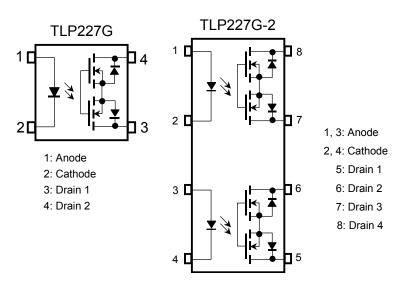
• Option(D4) type

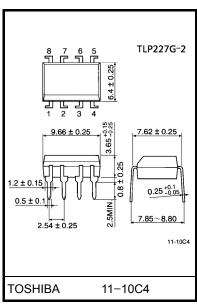
TUV approved: DIN EN 60747-5-2, certificate no. 40011913

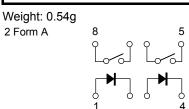
## 

Weight: 0.26g
1 Form A
4
3
1
2

## Pin Configuration (top view)



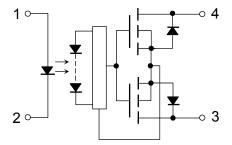




#### IOSHIBA

#### **Internal Circuit**

(TLP227G)



#### Absolute Maximum Ratings (Ta = 25°C)

	Characteristic					Rating	Unit	
	Forward current	ΙF	50	mA				
	Forward current derating	g(Ta ≥ 25°C)	ΔI <sub>F</sub> / °C	-0.5	mA / °C			
Ω	Peak forward current(10	00μs pulse, 100pp	s)		I <sub>FP</sub>	1	Α	
LED	Reverse voltage				V <sub>R</sub>	5	V	
	Junction temperature		Tj	125	°C			
	Off-state output terminal	V <sub>OFF</sub>	350	V				
	On-state current	TLP227G				120		
		TLP227G-2	One channel		I <sub>ON</sub>	120	mA	
ō		TLP227G-2	Both channel	(Note 1)		100		
Detector	_	TLP227G			1	-1.2		
Ď	On-state current derating(Ta ≥ 25°C)	TLP227G-2	One channel		ΔI <sub>ON</sub> / °C	-1.2	mA / °C	
		TLP227G-2	Both channel	(Note 1)		-1.0		
	Junction temperature			Tj	125	°C		
Sto	rage temperature range		T <sub>stg</sub>	<b>−55~125</b>	°C			
Оре	erating temperature range	T <sub>opr</sub>	<b>−40~85</b>	°C				
Lea	d soldering temperature (	(10 s)	T <sub>sol</sub>	260	°C			
Isol	ation voltage (AC,1 min.,	R.H.≤ 60%)	BVS	2500	V <sub>rms</sub>			

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1): Two channels operating simultaneously.

(Note 2): Device considered a two-terminal device: LED side pins shorted together, and detector side pins shorted together.

#### **Recommended Operating Conditions**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	$V_{DD}$	_	_	280	V
Forward current	lF	5	7.5	25	mA
On-state current	I <sub>ON</sub>	_	_	100	mA
Operating temperature	T <sub>opr</sub>	-20	_	65	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

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## Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	$V_{F}$	I <sub>F</sub> =10mA	1.0	1.15	1.3	V
LED	Reverse current	I <sub>R</sub>	V <sub>R</sub> =5V	_	_	10	μΑ
	Capacitance	C <sub>T</sub>	V=0,f=1MHz	_	30	_	pF
or	Off-state current	l <sub>OFF</sub>	V <sub>OFF</sub> =350V	_	_	1	μA
Detector	Capacitance	C <sub>OFF</sub>	V=0,f=1MHz	ı	40	ı	pF

#### **Coupled Electrical Characteristics (Ta = 25°C)**

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I <sub>FT</sub>	I <sub>ON</sub> =120mA	_	2	3	mA
On-state resistance	R <sub>ON</sub>	I <sub>ON</sub> =120mA,I <sub>F</sub> =5mA	-	22	35	Ω
		I <sub>ON</sub> =20~120mA,	_	26	40	
		I <sub>F</sub> =5mA				

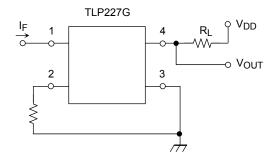
## **Isolation Characteristics (Ta = 25°C)**

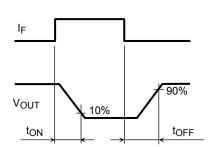
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance input to output	CS	V <sub>S</sub> =0,=1MHz	_	0.8	_	pF
Isolation resistance	R <sub>S</sub>	V <sub>S</sub> =500V,R.H.≤ 60%	5×10 <sup>10</sup>	10 <sup>14</sup>	_	Ω
	BVS	AC,1 minute	2500	_	-	- V <sub>rms</sub>
Isolation voltage		AC,1 second(in oil)	_	5000	-	
		DC,1 minute(in oil)	_	5000	_	V <sub>dc</sub>

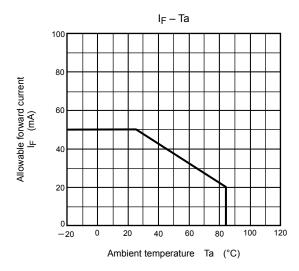
## **Switching Characteristics (Ta = 25°C)**

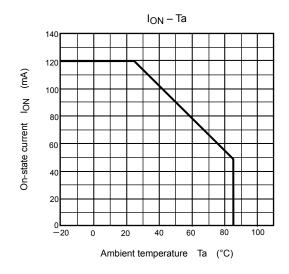
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t <sub>ON</sub>	R <sub>L</sub> =200Ω	_	0.3	1	ms
Turn-off time	tOFF	V <sub>DD</sub> =20V,I <sub>F</sub> =5mA	_	0.1	1	1115

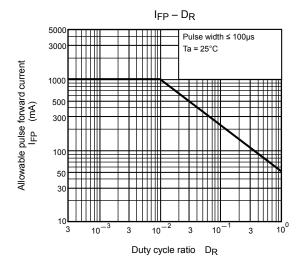
## **Switching Time Test Circuit**

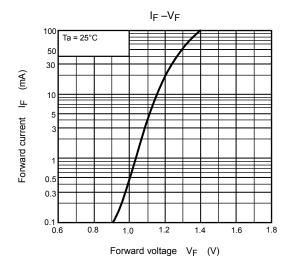


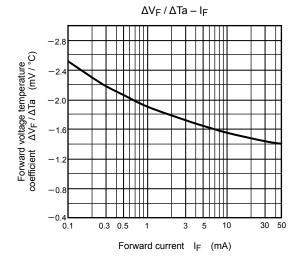


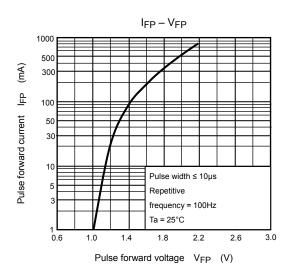


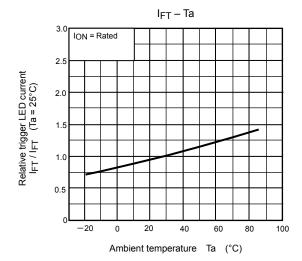


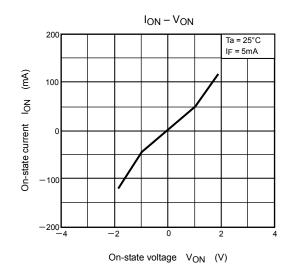


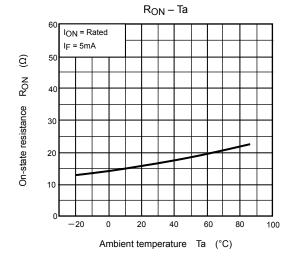


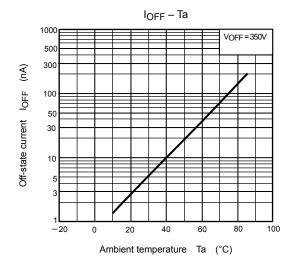












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20070701-EN

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